NSN 5961-01-166-5928

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-166-5928 **Inclosure Material:** Metal **Overall Length:** 0.375 inches **Function For Which Designed:** Bidirectional **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.429 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 15.8 breakdown voltage, dc and 12.8 reverse voltage, dc **Current Rating Per Characteristic:** 21.20 amperes source cutoff current universal **Power Rating Per Characteristic:** 5.0 watts any acceptable absolute **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0